HEF4077B

Quad 2-input EXCLUSIVE-NOR gate

Rev. 4 — 18 July 2014

Product data sheet

1. General description

The HEF4077B is a quad 2-input EXCLUSIVE-NOR gate. The outputs are fully buffered for the highest noise immunity and pattern insensitivity to output impedance.

The HEF4077B operates over a recommended V_{DD} power supply range of 3 V to 15 V referenced to V_{SS} (usually ground). Unused inputs must be connected to V_{DD} , V_{SS} , or another input.

2. Features and benefits

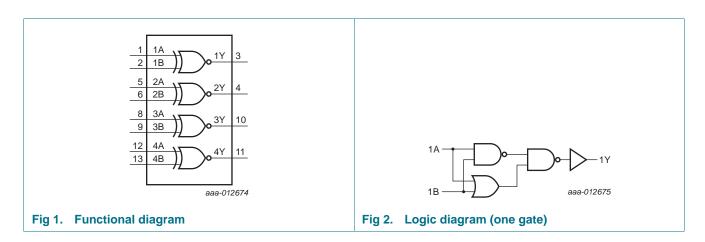
- Fully static operation
- 5 V, 10 V, and 15 V parametric ratings
- Standardized symmetrical output characteristics
- Specified from -40 °C to +85 °C
- Complies with JEDEC standard JESD 13-B

3. Ordering information

Table 1. Ordering information

Type number	Package							
	Temperature range	Name	Description	Version				
HEF4077BP	-40 °C to +85 °C	DIP14	plastic dual in-line package; 14 leads (300 mil)	SOT27-1				
HEF4077BT	–40 °C to +85 °C	SO14	plastic small outline package; 14 leads; body width 3.9 mm	SOT108-1				

4. Functional diagram

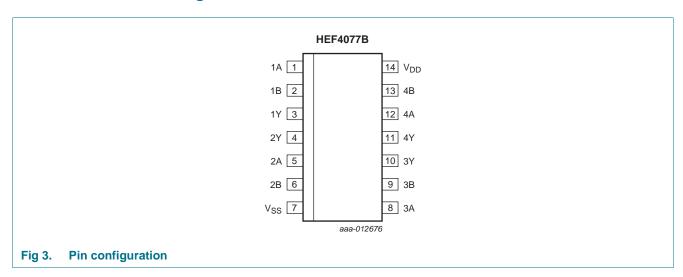




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5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
1A to 4A	1, 5, 8, 12	input
1B to 4B	2, 6, 9, 13	input
1Y to 4Y	3, 4, 10, 11	output
V _{SS}	7	ground (0 V)
V_{DD}	14	supply voltage

6. Functional description

Table 3. Functional table[1]

Input		Output
nA	nB	nY
L	L	Н
L	Н	L
Н	L	L
Н	Н	Н

^[1] H = HIGH voltage level; L = LOW voltage level.

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7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to V_{SS} = 0 V (ground).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DD}	supply voltage		-0.5	+18	V
I _{IK}	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{DD} + 0.5 \text{ V}$	-	±10	mA
VI	input voltage		-0.5	V _{DD} + 0.5	V
I _{OK}	output clamping current	$V_{O} < -0.5 \text{ V or } V_{O} > V_{DD} + 0.5 \text{ V}$	-	±10	mA
I _{I/O}	input/output current		-	±10	mA
I _{DD}	supply current		-	50	mA
T _{stg}	storage temperature		-65	+150	°C
T _{amb}	ambient temperature		-40	+85	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } + 85 ^{\circ}\text{C}$			
		DIP14	[1] -	750	mW
		SO14	[2] -	500	mW
Р	power dissipation	per output	-	100	mW

^[1] For DIP14 packages: above T_{amb} = 70 °C, P_{tot} derates linearly with 12 mW/K.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DD}	supply voltage		3	15	V
VI	input voltage		0	V_{DD}	V
T _{amb}	ambient temperature	in free air	-40	+85	°C
Δt/ΔV	input transition rise and fall rate	V _{DD} = 5 V	-	3.75	μs/V
		$V_{DD} = 10 \text{ V}$	-	0.5	μs/V
		V _{DD} = 15 V	-	0.08	μs/V

^[2] For SO14 packages: above T_{amb} = 70 °C, P_{tot} derates linearly with 8 mW/K.

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9. Static characteristics

Table 6. Static characteristics

 $V_{SS} = 0$ V; $V_I = V_{SS}$ or V_{DD} ; unless otherwise specified.

Symbol	Parameter	Conditions	V_{DD}	T _{amb} =	–40 °C	T _{amb} =	+25 °C	T _{amb} = +85 °C		Unit
				Min	Max	Min	Max	Min	Max	
V _{IH}	HIGH-level	I _O < 1 μA	5 V	3.5	-	3.5	-	3.5	-	V
	input voltage		10 V	7.0	-	7.0	-	7.0	-	V
			15 V	11.0	-	11.0	-	11.0	-	V
V_{IL}	LOW-level	I _O < 1 μA	5 V	-	1.5	-	1.5	-	1.5	V
	input voltage		10 V	-	3.0	-	3.0	-	3.0	V
			15 V	-	4.0	-	4.0	-	4.0	V
V _{OH}	HIGH-level	I _O < 1 μA	5 V	4.95	-	4.95	-	4.95	-	V
	output voltage		10 V	9.95	-	9.95	-	9.95	-	V
			15 V	14.95	-	14.95	-	14.95	-	V
V _{OL}	LOW-level	I _O < 1 μA	5 V	-	0.05	-	0.05	-	0.05	V
	output voltage		10 V	-	0.05	-	0.05	-	0.05	V
			15 V	-	0.05	-	0.05	-	0.05	V
I _{OH}	HIGH-level	V _O = 2.5 V	5 V	-	-1.7	-	-1.4	-	-1.1	mΑ
	output current	$V_0 = 4.6 \text{ V}$	5 V	-	-0.52	-	-0.44	-	-0.36	mΑ
		$V_0 = 9.5 \text{ V}$	10 V	-	-1.3	-	-1.1	-	-0.9	mΑ
		V _O = 13.5 V	15 V	-	-3.6	-	-3.0	-	-2.4	mΑ
I _{OL}	LOW-level	V _O = 0.4 V	5 V	0.52	-	0.44	-	0.36	-	mΑ
	output current	$V_0 = 0.5 \text{ V}$	10 V	1.3	-	1.1	-	0.9	-	mΑ
		V _O = 1.5 V	15 V	3.6	-	3.0	-	2.4	-	mΑ
II	input leakage current		15 V	-	±0.3	-	±0.3	-	±3.0	μΑ
I _{DD}	supply current	all valid input combinations;	5 V	-	1.0	-	1.0	-	7.5	μΑ
		$I_O = 0 A$	10 V	-	2.0	-	2.0	-	15.0	μΑ
			15 V	-	4.0	-	4.0	-	30.0	μΑ
Cı	input capacitance			-	-	-	7.5	-	-	pF

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10. Dynamic characteristics

Table 7. Dynamic characteristics

 T_{amb} = 25 °C; waveforms see <u>Figure 4</u>; test circuit, see <u>Figure 5</u>; unless otherwise specified. [1]

Symbol	Parameter	Conditions	V_{DD}	Extrapolation formula	Min	Тур	Max	Unit
t _{PHL}	HIGH to LOW	nA or nB to nY	5 V	48 ns + (0.55 ns/pF)C _L	-	75	150	ns
	propagation delay		10 V	24 ns + (0.23 ns/pF)C _L	-	35	70	ns
			15 V	22 ns + (0.16 ns/pF)C _L	-	30	55	ns
t _{PLH}	LOW to HIGH	nA or nB to nY	5 V	43 ns + (0.55 ns/pF)C _L	-	70	145	ns
	propagation delay		10 V	19 ns + (0.23 ns/pF)C _L	-	30	60	ns
			15 V	17 ns + (0.16 ns/pF)C _L	-	25	50	ns
t _t	transition time		5 V [2]	10 ns + (1.00 ns/pF)C _L	-	60	120	ns
			10 V	9 ns + (0.42 ns/pF)C _L	-	30	60	ns
			15 V	6 ns + (0.28 ns/pF)C _L	-	20	40	ns

^[1] The typical value of the propagation delay and output transition time can be calculated with the extrapolation formula (C_L in pF).

Table 8. Dynamic power dissipation

 $V_{SS} = 0 \text{ V; } t_r = t_f \le 20 \text{ ns; } T_{amb} = 25 \text{ °C.}$

Symbol	Parameter	V_{DD}	Typical formula	where:
P_D	dynamic power dissipation	5 V	$P_D = 850 \times f_i + \Sigma (f_0 \times C_L) \times V_{DD}^2 (\mu W)$	f _i = input frequency in MHz;
		10 V	$P_D = 4500 \times f_i + \Sigma (f_o \times C_L) \times V_{DD}^2 (\mu W)$	fo = output frequency in MHz;
		15 V	$P_D = 114700 \times f_i + \Sigma (f_o \times C_L) \times V_{DD}^2$	C_L = output load capacitance in pF;
			(μW)	$\Sigma(f_0 \times C_L) = \text{sum of the outputs};$
				V _{DD} = supply voltage in V.

11. Waveforms

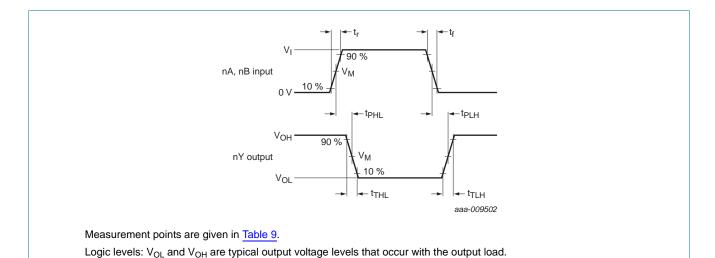


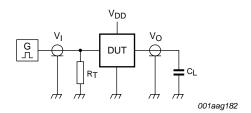
Fig 4. Input to output propagation delay and output transition times

^[2] t_t is the same as t_{THL} and t_{TLH} .

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Table 9. Measurement points

Supply voltage	Input	Output	
V_{DD}	V _M	V _M	
5 V to 15 V	0.5V _{DD}	0.5V _{DD}	



Test data is given in Table 10.

Definitions for test circuit:

DUT = Device Under Test.

 C_L = load capacitance including jig and probe capacitance.

 R_T = termination resistance should be equal to the output impedance Z_0 of the pulse generator.

Fig 5. Test circuit

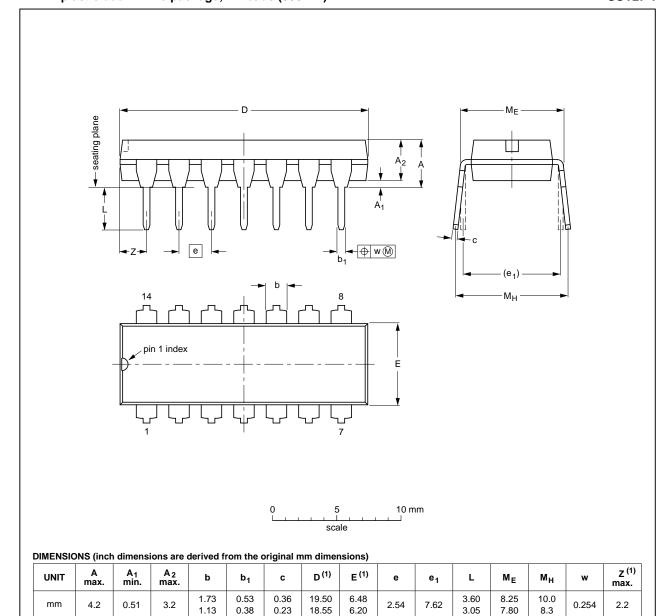
Table 10. Test data

Supply voltage	Input	Load	
V_{DD}	VI	t _r , t _f	CL
5 V to 15 V	V _{SS} or V _{DD}	≤ 20 ns	50 pF

12. Package outline

DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1



. . .

inches

0.17

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

0.068

0.044

0.021

0.015

0.014

0.009

0.77

0.26

0.1

0.3

0.14

0.32

0.39

OUTLINE	REFERENCES			EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT27-1	050G04	MO-001	SC-501-14		99-12-27 03-02-13

Fig 6. Package outline SOT27-1 (DIP14)

0.02

0.13

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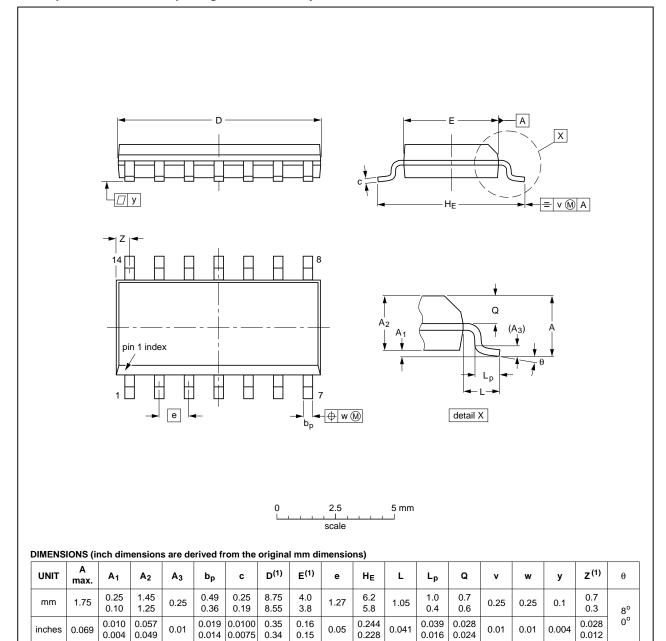
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0.087

0.01

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT108-1	076E06	MS-012				99-12-27 03-02-19

Fig 7. Package outline SOT108-1 (SO14)

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13. Abbreviations

Table 11. Abbreviations

Acronym	Description
CDM	Charged-Device Model
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
HEF4077B v.4	20140718	Product data sheet	-	HEF4077B_CNV_3		
Modifications:	 The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. 					
	 Legal texts have been adapted to the new company name where appropriate. 					
	Data sheet is imported into latest template.					
HEF4077B_CNV_3	19950101	Product specification	-	-		

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Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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